

Description

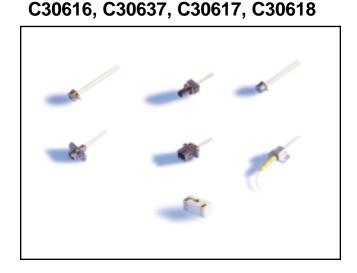
High-speed InGaAs photodiodes from PerkinElmer Optoelectronics are designed for use in OEM fiber optic communications systems and high-speed receiver applications including trunk line, LAN, fiber-in-the-loop and data communications. Ceramic submount packages are available for easy integration into high-speed SONET, FDDI, or datalink receiver modules, or as back-facet power monitors in laser diode modules.

Photodiodes are available in hermetic TO-18 packages, or in connectorized receptacle packages with industry standard ST, FC or SC connectors. These are designed for mating to either single or multimode fibers. Photodiodes are also available in a fibered package with either single or multimode fiber pigtail, which can be terminated with either an ST, FC or SC connector. Receptacled and fibered packages use a ball-lens TO-18 package to maximize coupling efficiency. All devices are planar passivated and feature proven high reliability mounting and contacting. An MTTF of >10° hours (approximately 105 years) at 50°C has been demonstrated to date from standard production samples.

Quality and Reliability

PerkinElmer Optoelectronics is committed to supplying the highest quality product to our customers, and we are certified to meet ISO-9001 and operate to MIL-Q-9858A and AQAP-1 quality standards. Process control is maintained through annual requalification of production units and includes extensive electrical, thermal and mechanical stress as well as an extended lifetest. In addition, every wafer lot is individually qualified to meet responsivity, capacitance and dark current specifications, and reliability is

High-Speed InGaAs PIN Photodiodes



demonstrated with an extended high temperature burnin at 200°C for 168 hours ($V^R = 10V$), ensuring an MTTF > 10^7 hours at 50°C ($E_A = 0.7eV$). Finally, all production devices are screened with a 16 hour, 200°C burn-in ($V^R = 10V$) and tested to meet responsivity, spectral noise and dark current specifications.

Features

- 50, 75, 100, 350 µm diameters
- High responsivity at 1300 and 1550nm
- Low capacitance for high bandwidths (to 3.5GHz)
- Available in various package options

Applications

- · High-speed communications
- SONET/ATM, FDDI
- Datalinks & LANs
- Fiber optic sensors





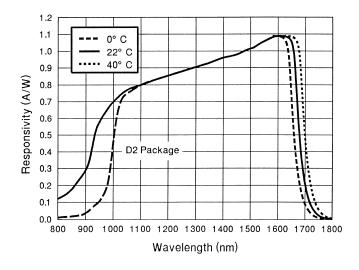
EVERYTHING

IN A

NEW

LIGHT.

Parameter	C30616			C30637			
	Min	Тур	Max	Min	Тур	Max	Units
Operating Voltage	1	5	10	1	5	10	V
Breakdown Voltage	25	100		25	100		V
Active Diameter		50			75		μm
Responsivity at 1300 nm							
Ceramic (D1)	0.80	0.90		0.80	0.90		A/W
Responsivity at 1550 nm							
Ceramic (D1)	0.85	0.95		0.85	0.95		A/W
Dark Current		< 1.0	2.0		< 1.0	2.0	nA
Spectral Noise Current (10 kHz, 1.0 Hz)		< 0.02	0.15		< 0.02	0.15	pA/√Hz
Capacitance at $V_R = V_{OP}$ (typ)							
Ceramic (D1)		0.35	0.55		0.40	0.60	pF
Rise/Fall Time (10% to 90%)		0.07	0.5		0.07	0.5	ns
Bandwidth (-3 dB, $R_L = 50\Omega$)		3.5			3.5		GHz
Available Package Types		D1			D1		
Maximum Ratings							
Maximum Forward Current			10			10	mA
Power Dissipation			100			100	mW
Storage Temperature	-60		125	-60		125	°C
Operating Temperature	-40		125	-40		125	°C



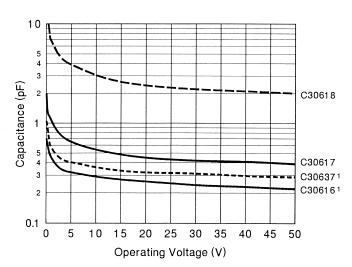


Figure 1: Typical spectral responsivity vs wavelength.

Dotted line shows response in D2 package (silicon window)

Figure 2: Typical capacitance vs operating voltage. Note 1: Ceramic submount.

Specifications (at $V_R = V_{OP}$ typical), 22°C

Parameter	C30617			C30618			
	Min	Тур	Max	Min	Тур	Max	Units
Operating Voltage	1	5	10	1	5	10	V
Breakdown Voltage	25	100		25	80		V
Active Diameter		100			350		μm
Responsivity at 1300 nm							
Ceramic (D1)/TO-18 (D2)	0.80	0.90		0.80	0.90		A/W
Fiber (D6)/FC (D4)/ST (D3)/SC (D5)1	0.65	0.75		0.65	0.75		
Responsivity at 1550 nm							
Ceramic (D1)/TO-18 (D2)	0.85	0.95		0.85	0.95		A/W
Fiber (D6)/FC (D4)/ST (D3)/SC (D5)1	0.70	0.80		0.70	0.80		
Dark Current		< 1.0	2.0		2.0	5.0	nA
Spectral Noise Current (10 kHz, 1.0 Hz)		< 0.02	0.15		0.02	0.20	pA/√Hz
Capacitance at $V_R = V_{OP}$ (typ)							
(D1),(D6),(D3),(D5)		0.6	0.8		4.0	6.0	pF
TO-18 (D2)		0.8	1.0		4.0	6.0	
Rise/Fall Time (10% to 90%)		0.07	0.5		0.5	1.0	ns
Bandwidth (-3 dB, $R_L = 50 \Omega$)		3.5			0.75		GHz
Available Package Types	D1,	D2, D3, D	4, D5, D6,	D1,	D2, D3,	D4, D21	-

Maximum Forward Current		10		10	mA	
Power Dissipation		100		100	mW	
Storage Temperature ²	-60	125	-60	125	°C	
Operating Temperature ²	-40	125	-40	125	°C	

Note 1. Coupled from 62.5 Fm, 0.28 NA graded index multi-mode fiber using 1300 nm SLED source.

Note 2. Maximum storage and operating temperature for connectorized and fibered devices is $+85^{\circ}\text{C}$.

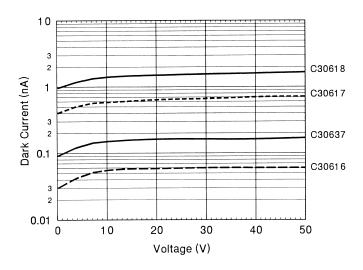


Figure 3: Typical dark current vs. voltage

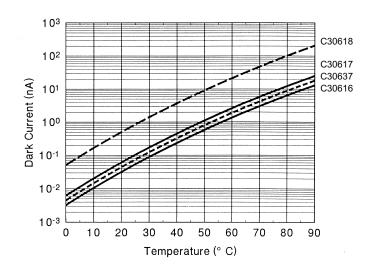


Figure 4: Typical dark current vs. temperature at $V_{\mbox{OP}}$ = -5V.

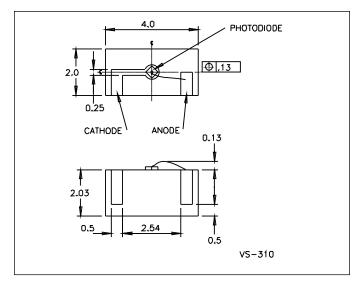


Figure 5: Package D1: Ceramic Submount

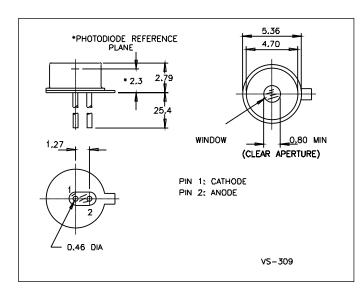


Figure 6: Package D2: TO-18 low profile

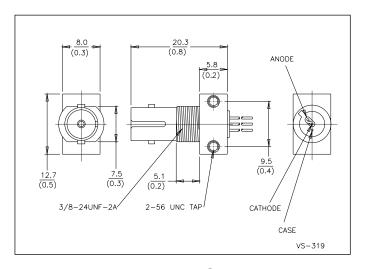


Figure 7: Package D3: ST receptacle module

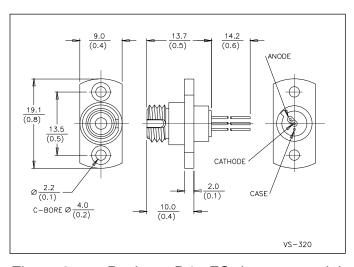


Figure 8: Package D4: FC detector module

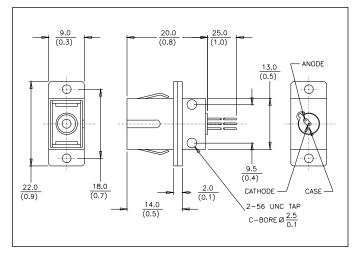


Figure 9: Package D5: SC receptacle module

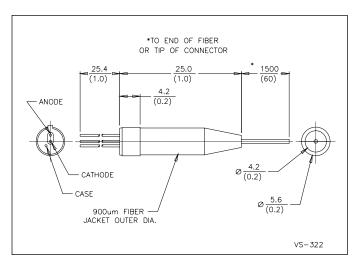
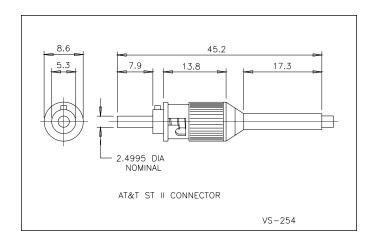


Figure 10: Package D6: Fibered detector module



2.4995 DIA 57.2 NOMINAL 9.7 14.0 38.1 38.1 3.9 3.9 3M FC CONNECTOR VS-253

Figure 11: Termination D8: ST connector

Figure 12: Termination D9: FC connector

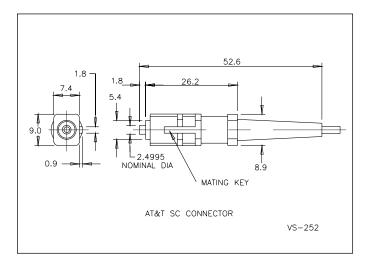


Figure 13: Termination D10: SC connector

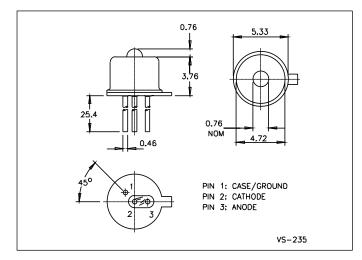
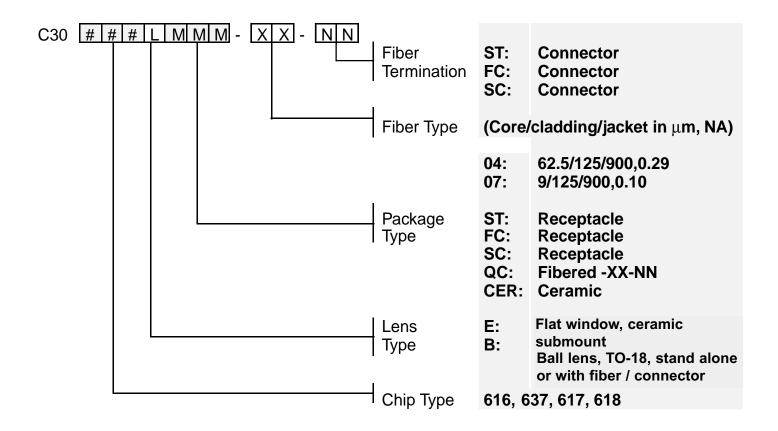


Figure 14: Package D21: TO-18 ball-lens package





Note: Specific package types available for each photodiode are listed in the table of specifications.

For more information e-mail us at opto@perkinelmer.com or visit our web site at www.perkinelmer.com/opto



PerkinElmer Optoelectronics 22001 Dumberry Road Vaudreuil (QC) Canada J7V 8P7 Phone: (450) 424-3300

Fax: (450) 424-3411